74AHC1G125-Q100; 74AHCT1G125-Q100

Bus buffer/line driver; 3-state Rev. 6 — 19 September 2024

**Product data sheet** 

### 1. General description

The 74AHC1G125-Q100/74AHCT1G125-Q100 is a single buffer/line driver with 3-state output. Inputs are overvoltage tolerant. This feature allows the use of these devices as translators in mixed voltage environments.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

### 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - Specified from -40 °C to +85 °C and -40 °C to +125 °C
- Wide supply voltage range from 2.0 V to 5.5 V
- Overvoltage tolerant inputs to 5.5 V
- High noise immunity
- Symmetrical output impedance
- CMOS low power dissipation
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level A
- Balanced propagation delays
- Input levels:
  - For 74AHC1G125-Q100: CMOS level
  - For 74AHCT1G125-Q100: TTL level
- ESD protection:
  - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
  - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V

### 3. Ordering information

| Type number                             | Package           |        |   |                  |
|---|-------------------|--------|---|------------------|
|   | Temperature range | Name   | Description   | Version          |
| 74AHC1G125GW-Q100<br>74AHCT1G125GW-Q100 | -40 °C to +125 °C | TSSOP5 | plastic thin shrink small outline package;<br>5 leads; body width 1.25 mm   | <u>SOT353-1</u>  |
| 74AHC1G125GV-Q100<br>74AHCT1G125GV-Q100 | -40 °C to +125 °C | SC-74A | plastic surface-mounted package; 5 leads  | <u>SOT753</u>    |
| 74AHC1G125GZ-Q100                       | -40 °C to +125 °C | XSON5  | plastic thermal enhanced extremely thin<br>small outline package with side-wettable<br>flanks (SWF); no leads; 5 terminals;<br>body 1.1 × 0.85 × 0.5 mm | <u>SOT8065-1</u> |

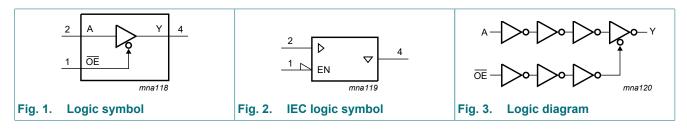
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### 4. Marking

| Type number        | Marking [1] |
|--------------------|-------------|
| 74AHC1G125GW-Q100  | AM          |
| 74AHCT1G125GW-Q100 | СМ          |
| 74AHC1G125GV-Q100  | A25         |
| 74AHCT1G125GV-Q100 | C25         |
| 74AHC1G125GZ-Q100  | AM          |

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

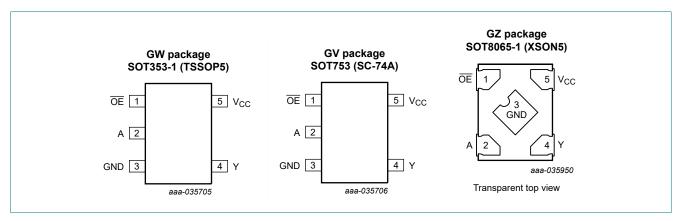
### 5. Functional diagram



### 6. Pinning information

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### 6.1. Pinning



### 6.2. Pin description

| Table 3. Pin descriptio | n   |                     |
|-------------------------|-----|---------------------|
| Symbol                  | Pin | Description         |
| OE                      | 1   | output enable input |
| A                       | 2   | data input          |
| GND                     | 3   | ground (0 V)        |
| Y                       | 4   | data output         |
| V <sub>CC</sub>         | 5   | supply voltage      |

### 7. Functional description

#### Table 4. Function table

H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

| Inputs |   | Output |
|--------|---|--------|
| OE     | A | Y      |
| L      | L | L      |
| L      | Н | Н      |
| Н      | X | Z      |

### 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter               | Conditions  | Min  | Мах  | Unit |
|------------------|-------------------------|---|------|------|------|
| V <sub>CC</sub>  | supply voltage          |   | -0.5 | +7.0 | V    |
| VI               | input voltage           |   | -0.5 | +7.0 | V    |
| I <sub>IK</sub>  | input clamping current  | V <sub>I</sub> < -0.5 V [1]   | -20  | -    | mA   |
| I <sub>ОК</sub>  | output clamping current | $V_{\rm O} < -0.5 \text{ V or } V_{\rm O} > V_{\rm CC} + 0.5 \text{ V}$ [1] | -    | ±20  | mA   |
| I <sub>O</sub>   | output current          | $-0.5 V < V_O < V_{CC} + 0.5 V$   | -    | ±25  | mA   |
| I <sub>CC</sub>  | supply current          |   | -    | 75   | mA   |
| I <sub>GND</sub> | ground current          |   | -75  | -    | mA   |
| T <sub>stg</sub> | storage temperature     |   | -65  | +150 | °C   |
| P <sub>tot</sub> | total power dissipation | $T_{amb} = -40 \text{ °C to } +125 \text{ °C}$ [2]                          | -    | 250  | mW   |

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SOT353-1 (TSSOP5) package:  $P_{tot}$  derates linearly with 3.3 mW/K above 74 °C.

For SOT753 (SC-74A) package: P<sub>tot</sub> derates linearly with 3.8 mW/K above 85 °C.

For SOT8065-1 (XSON5) package:  $P_{tot}$  derates linearly with 3.2 mW/K above 72 °C.

### 9. Recommended operating conditions

#### Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter                 | Conditions                      | 74AH | 74AHC1G125-Q100 |                 |     | 74AHCT1G125-Q100 |                 |      |  |
|------------------|---------------------------|---------------------------------|------|-----------------|-----------------|-----|------------------|-----------------|------|--|
|                  |                           |                                 | Min  | Тур             | Max             | Min | Тур              | Max             |      |  |
| V <sub>CC</sub>  | supply voltage            |                                 | 2.0  | 5.0             | 5.5             | 4.5 | 5.0              | 5.5             | V    |  |
| VI               | input voltage             |                                 | 0    | -               | 5.5             | 0   | -                | 5.5             | V    |  |
| Vo               | output voltage            |                                 | 0    | -               | V <sub>CC</sub> | 0   | -                | V <sub>CC</sub> | V    |  |
| T <sub>amb</sub> | ambient temperature       |                                 | -40  | +25             | +125            | -40 | +25              | +125            | °C   |  |
| Δt/ΔV            | input transition rise and | V <sub>CC</sub> = 3.3 V ± 0.3 V | -    | -               | 100             | -   | -                | -               | ns/V |  |
|                  | fall rate                 | V <sub>CC</sub> = 5.0 V ± 0.5 V | -    | -               | 20              | -   | -                | 20              | ns/V |  |

### **10. Static characteristics**

#### Table 7. Static characteristics

Voltages are referenced to GND (ground = 0 V).

| Symbol          | Parameter                   | Conditions   |      | 25 °C |      | -40 °C | to +85 °C | -40 °C t | o +125 °C | Unit |
|-----------------|-----------------------------|--|------|-------|------|--------|-----------|----------|-----------|------|
|                 |                             |  | Min  | Тур   | Max  | Min    | Max       | Min      | Max       |      |
| 74AHC1          | G125-Q100                   | 1  |      |       |      | 1      |           |          |           |      |
| VIH             | HIGH-level                  | V <sub>CC</sub> = 2.0 V  | 1.5  | -     | -    | 1.5    | -         | 1.5      | -         | V    |
|                 | input voltage               | V <sub>CC</sub> = 3.0 V  | 2.1  | -     | -    | 2.1    | -         | 2.1      | -         | V    |
|                 |                             | V <sub>CC</sub> = 5.5 V  | 3.85 | -     | -    | 3.85   | -         | 3.85     | -         | V    |
| V <sub>IL</sub> | LOW-level                   | V <sub>CC</sub> = 2.0 V  | -    | -     | 0.5  | -      | 0.5       | -        | 0.5       | V    |
|                 | input voltage               | V <sub>CC</sub> = 3.0 V  | -    | -     | 0.9  | -      | 0.9       | -        | 0.9       | V    |
|                 |                             | V <sub>CC</sub> = 5.5 V  | -    | -     | 1.65 | -      | 1.65      | -        | 1.65      | V    |
| V <sub>OH</sub> | HIGH-level                  | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>              |      |       |      |        |           |          |           |      |
|                 | output voltage              | I <sub>O</sub> = -50 μA; V <sub>CC</sub> = 2.0 V                 | 1.9  | 2.0   | -    | 1.9    | -         | 1.9      | -         | V    |
|                 |                             | I <sub>O</sub> = -50 μA; V <sub>CC</sub> = 3.0 V                 | 2.9  | 3.0   | -    | 2.9    | -         | 2.9      | -         | V    |
|                 |                             | I <sub>O</sub> = -50 μA; V <sub>CC</sub> = 4.5 V                 | 4.4  | 4.5   | -    | 4.4    | -         | 4.4      | -         | V    |
|                 |                             | I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V                | 2.58 | -     | -    | 2.48   | -         | 2.40     | -         | V    |
|                 |                             | I <sub>O</sub> = -8.0 mA; V <sub>CC</sub> = 4.5 V                | 3.94 | -     | -    | 3.8    | -         | 3.70     | -         | V    |
| V <sub>OL</sub> | LOW-level                   | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>              |      |       |      |        |           |          |           |      |
|                 | output voltage              | I <sub>O</sub> = 50 μA; V <sub>CC</sub> = 2.0 V                  | -    | 0     | 0.1  | -      | 0.1       | -        | 0.1       | V    |
|                 |                             | I <sub>O</sub> = 50 μA; V <sub>CC</sub> = 3.0 V                  | -    | 0     | 0.1  | -      | 0.1       | -        | 0.1       | V    |
|                 |                             | I <sub>O</sub> = 50 μA; V <sub>CC</sub> = 4.5 V                  | -    | 0     | 0.1  | -      | 0.1       | -        | 0.1       | V    |
|                 |                             | I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V                 | -    | -     | 0.36 | -      | 0.44      | -        | 0.55      | V    |
|                 |                             | I <sub>O</sub> = 8.0 mA; V <sub>CC</sub> = 4.5 V                 | -    | -     | 0.36 | -      | 0.44      | -        | 0.55      | V    |
| I <sub>OZ</sub> | OFF-state<br>output current | $V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5 V$                        | -    | -     | 0.25 | -      | 2.5       | -        | 10        | μA   |
| l <sub>l</sub>  | input leakage<br>current    | V <sub>I</sub> = 5.5 V or GND;<br>V <sub>CC</sub> = 0 V to 5.5 V | -    | -     | 0.1  | -      | 1.0       | -        | 2.0       | μA   |
| I <sub>CC</sub> | supply current              | $V_I = V_{CC}$ or GND; $I_O = 0$ A;<br>$V_{CC} = 5.5$ V          | -    | -     | 1.0  | -      | 10        | -        | 40        | μA   |
| CI              | input<br>capacitance        |  | -    | 1.5   | 10   | -      | 10        | -        | 10        | pF   |
| 74AHCT          | 1G125-Q100                  | 1  |      |       |      |        |           |          |           |      |
| V <sub>IH</sub> | HIGH-level<br>input voltage | $V_{CC}$ = 4.5 V to 5.5 V  | 2.0  | -     | -    | 2.0    | -         | 2.0      | -         | V    |
| V <sub>IL</sub> | LOW-level input voltage     | $V_{CC}$ = 4.5 V to 5.5 V  | -    | -     | 0.8  | -      | 0.8       | -        | 0.8       | V    |
| V <sub>OH</sub> | HIGH-level                  | $V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$      |      |       |      |        |           |          |           |      |
| -               | output voltage              | I <sub>O</sub> = -50 μA  | 4.4  | 4.5   | -    | 4.4    | -         | 4.4      | -         | V    |
|                 |                             | I <sub>O</sub> = -8.0 mA   | 3.94 | -     | -    | 3.8    | -         | 3.70     | -         | V    |
| V <sub>OL</sub> | LOW-level                   | $V_{I} = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5$ V                  |      |       |      |        |           |          |           |      |
|                 | output voltage              | I <sub>O</sub> = 50 μA   | -    | 0     | 0.1  | -      | 0.1       | -        | 0.1       | V    |
|                 |                             | $I_0 = 8.0 \text{ mA}$   | -    | -     | 0.36 | -      | 0.44      | _        | 0.55      | V    |

| Symbol           | Parameter                   | Conditions   |     | 25 °C |      | -40 °C 1 | to +85 °C | -40 °C t | Unit |    |
|------------------|-----------------------------|--|-----|-------|------|----------|-----------|----------|------|----|
|                  |                             |  | Min | Тур   | Max  | Min      | Max       | Min      | Мах  |    |
| I <sub>OZ</sub>  | OFF-state<br>output current | $V_I = V_{CC}$ or GND; $V_{CC} = 5.5 V$  | -   | -     | 0.25 | -        | 2.5       | -        | 10   | μA |
| I <sub>I</sub>   | input leakage<br>current    | V <sub>I</sub> = 5.5 V or GND;<br>V <sub>CC</sub> = 0 V to 5.5 V   | -   | -     | 0.1  | -        | 1.0       | -        | 2.0  | μA |
| I <sub>CC</sub>  | supply current              | $V_I = V_{CC}$ or GND; $I_O = 0$ A;<br>$V_{CC} = 5.5$ V  | -   | -     | 1.0  | -        | 10        | -        | 40   | μA |
| ΔI <sub>CC</sub> | additional supply current   | per input pin; V <sub>I</sub> = 3.4 V;<br>other inputs at V <sub>CC</sub> or GND;<br>$I_O = 0 A$ ; V <sub>CC</sub> = 5.5 V | -   | -     | 1.35 | -        | 1.5       | -        | 1.5  | mA |
| CI               | input<br>capacitance        |  | -   | 1.5   | 10   | -        | 10        | -        | 10   | pF |

### **11. Dynamic characteristics**

#### Table 8. Dynamic characteristics

GND = 0 V; for test circuit see Fig. 6.

| Symbol           | Parameter                           | Conditions  |     |     | 25 °C |      | -40 °C to<br>+85 °C |      | -40 °C to<br>+125 °C |      | Unit |
|------------------|-------------------------------------|---|-----|-----|-------|------|---------------------|------|----------------------|------|------|
|                  |                                     |   |     | Min | Тур   | Мах  | Min                 | Max  | Min                  | Max  | ]    |
| 74AHC1           | G125-Q100                           |   |     |     |       |      |                     |      |                      |      |      |
| t <sub>pd</sub>  | propagation                         | A to Y; see <u>Fig. 4</u>   | [1] |     |       |      |                     |      |                      |      |      |
|                  | delay                               | $V_{CC}$ = 3.0 V to 3.6 V; C <sub>L</sub> = 15 pF   | [2] | -   | 4.7   | 8.0  | 1.0                 | 9.5  | 1.0                  | 11.5 | ns   |
|                  |                                     | $V_{CC}$ = 3.0 V to 3.6 V; C <sub>L</sub> = 50 pF   | [2] | -   | 6.6   | 11.5 | 1.0                 | 13.0 | 1.0                  | 14.5 | ns   |
|                  |                                     | $V_{CC}$ = 4.5 V to 5.5 V; C <sub>L</sub> = 15 pF   | [3] | -   | 3.4   | 5.5  | 1.0                 | 6.5  | 1.0                  | 7.0  | ns   |
|                  |                                     | $V_{CC}$ = 4.5 V to 5.5 V; C <sub>L</sub> = 50 pF   | [3] | -   | 4.8   | 7.5  | 1.0                 | 8.5  | 1.0                  | 9.5  | ns   |
| t <sub>en</sub>  | enable time                         | OE to Y; see Fig. 5   | [1] |     |       |      |                     |      |                      |      |      |
|                  |                                     | $V_{CC}$ = 3.0 V to 3.6 V; C <sub>L</sub> = 15 pF   | [2] | -   | 5.0   | 8.0  | 1.0                 | 9.5  | 1.0                  | 11.5 | ns   |
|                  |                                     | $V_{CC}$ = 3.0 V to 3.6 V; C <sub>L</sub> = 50 pF   | [2] | -   | 6.9   | 11.5 | 1.0                 | 13.0 | 1.0                  | 14.5 | ns   |
|                  |                                     | $V_{CC}$ = 4.5 V to 5.5 V; C <sub>L</sub> = 15 pF   | [3] | -   | 3.6   | 5.1  | 1.0                 | 6.0  | 1.0                  | 6.5  | ns   |
|                  |                                     | $V_{CC}$ = 4.5 V to 5.5 V; C <sub>L</sub> = 50 pF   | [3] | -   | 4.9   | 7.5  | 1.0                 | 8.5  | 1.0                  | 9.5  | ns   |
| t <sub>dis</sub> | disable time                        | OE to Y; see Fig. 5   | [1] |     |       |      |                     |      |                      |      |      |
|                  |                                     | $V_{CC}$ = 3.0 V to 3.6 V; C <sub>L</sub> = 15 pF   | [2] | -   | 6.0   | 9.7  | 1.0                 | 11.5 | 1.0                  | 12.5 | ns   |
|                  |                                     | $V_{CC}$ = 3.0 V to 3.6 V; C <sub>L</sub> = 50 pF   | [2] | -   | 8.3   | 13.2 | 1.0                 | 15.0 | 1.0                  | 16.5 | ns   |
|                  |                                     | $V_{CC}$ = 4.5 V to 5.5 V; C <sub>L</sub> = 15 pF   | [3] | -   | 4.1   | 6.8  | 1.0                 | 8.0  | 1.0                  | 8.5  | ns   |
|                  |                                     | $V_{CC}$ = 4.5 V to 5.5 V; C <sub>L</sub> = 50 pF   | [3] | -   | 5.7   | 8.8  | 1.0                 | 10.0 | 1.0                  | 11.0 | ns   |
| C <sub>PD</sub>  | power<br>dissipation<br>capacitance | per buffer; C <sub>L</sub> = 50 pF; f = 1 MHz;<br>V <sub>I</sub> = GND to V <sub>CC</sub> | [4] | -   | 9     | -    | -                   | -    | -                    | -    | pF   |

| Symbol             | Parameter   | Conditions  |     | 25 °C |     |     | -40 °C to<br>+85 °C |      | -40 °C to<br>+125 °C |      | Unit |
|--------------------|---|---|-----|-------|-----|-----|---------------------|------|----------------------|------|------|
|                    |   |   |     | Min   | Тур | Max | Min                 | Max  | Min                  | Max  |      |
| 74AHCT             | 1G125-Q100  |   |     |       |     |     |                     |      |                      |      |      |
| t <sub>pd</sub>    | propagation                                       | A to Y; see <u>Fig. 4</u>   | [1] |       |     |     |                     |      |                      |      |      |
| delay              | $V_{CC}$ = 4.5 V to 5.5 V; C <sub>L</sub> = 15 pF | [3]   | -   | 3.4   | 5.5 | 1.0 | 6.5                 | 1.0  | 7.0                  | ns   |      |
|                    |   | $V_{CC}$ = 4.5 V to 5.5 V; C <sub>L</sub> = 50 pF   | [3] | -     | 4.8 | 7.5 | 1.0                 | 8.5  | 1.0                  | 9.5  | ns   |
| t <sub>en</sub> er | enable time                                       | OE to Y; see <u>Fig. 5</u>  | [1] |       |     |     |                     |      |                      |      |      |
|                    |   | $V_{CC}$ = 4.5 V to 5.5 V; C <sub>L</sub> = 15 pF   | [3] | -     | 3.9 | 5.1 | 1.0                 | 6.0  | 1.0                  | 6.5  | ns   |
|                    |   | $V_{CC}$ = 4.5 V to 5.5 V; C <sub>L</sub> = 50 pF   | [3] | -     | 5.1 | 7.5 | 1.0                 | 8.5  | 1.0                  | 9.5  | ns   |
| t <sub>dis</sub>   | disable time                                      | OE to Y; see <u>Fig. 5</u>  | [1] |       |     |     |                     |      |                      |      |      |
|                    |   | $V_{CC}$ = 4.5 V to 5.5 V; C <sub>L</sub> = 15 pF   | [3] | -     | 4.5 | 6.8 | 1.0                 | 8.0  | 1.0                  | 8.5  | ns   |
|                    |   | $V_{CC}$ = 4.5 V to 5.5 V; C <sub>L</sub> = 50 pF   | [3] | -     | 6.1 | 8.8 | 1.0                 | 10.0 | 1.0                  | 11.0 | ns   |
| C <sub>PD</sub>    | power<br>dissipation<br>capacitance               | per buffer; C <sub>L</sub> = 50 pF; f = 1 MHz;<br>V <sub>I</sub> = GND to V <sub>CC</sub> | [4] | -     | 11  | -   | -                   | -    | -                    | -    | pF   |

[1]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

 $t_{en}$  is the same as  $t_{PZL}$  and  $t_{PZH}$ .

t<sub>dis</sub> is the same as  $\psi_{LL}$  and  $\psi_{ZH}$ . t<sub>dis</sub> is the same as  $t_{PLZ}$  and  $t_{PHZ}$ . [2] Typical values are measured at  $V_{CC} = 3.3 \text{ V}$ . [3] Typical values are measured at  $V_{CC} = 5.0 \text{ V}$ . [4]  $C_{PD}$  is used to determine the dynamic power dissipation  $P_D$  ( $\mu$ W).  $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$  where:

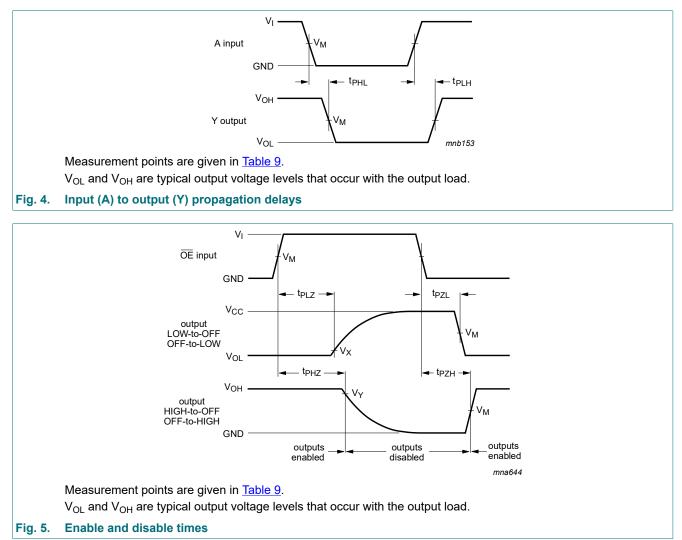
 $f_i$  = input frequency in MHz;

fo = output frequency in MHz;

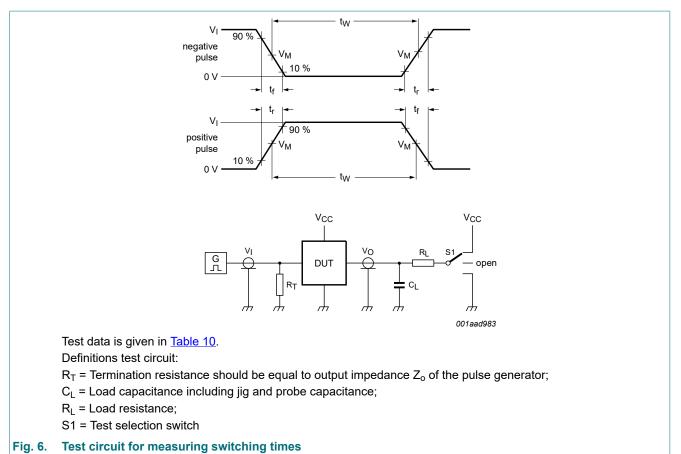
 $C_L$  = output load capacitance in pF;

 $V_{CC}$  = supply voltage in V.



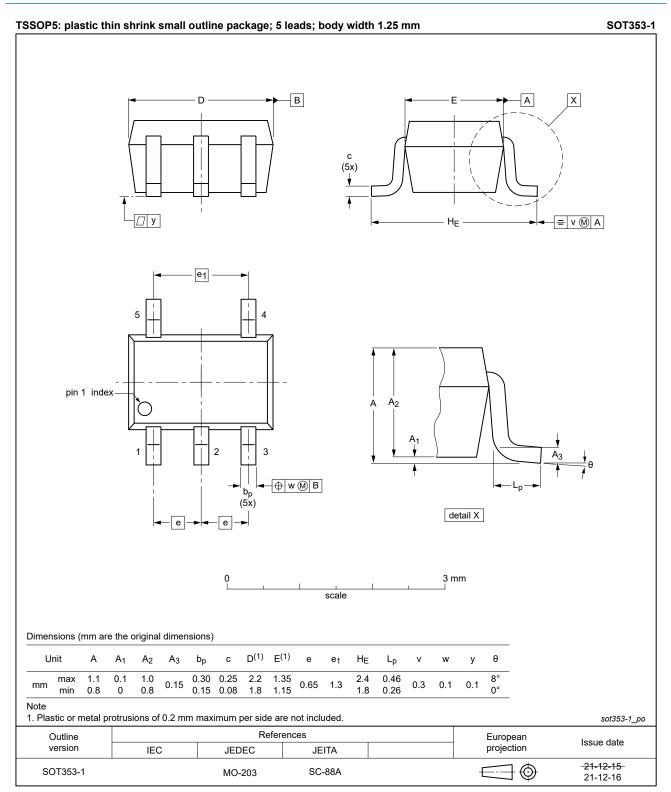


| Table 9. Measurement point |                        |                    |                    |                         |                         |  |  |  |  |  |
|----------------------------|------------------------|--------------------|--------------------|-------------------------|-------------------------|--|--|--|--|--|
| Туре                       | Inputs                 |                    | Output             |                         |                         |  |  |  |  |  |
|                            | VI                     | V <sub>M</sub>     | V <sub>M</sub>     | V <sub>X</sub>          | V <sub>Y</sub>          |  |  |  |  |  |
| 74AHC1G125-Q100            | GND to V <sub>CC</sub> | 0.5V <sub>CC</sub> | 0.5V <sub>CC</sub> | V <sub>OL</sub> + 0.3 V | V <sub>OH</sub> - 0.3 V |  |  |  |  |  |
| 74AHCT1G125-Q100           | GND to 3.0 V           | 1.5 V              | 0.5V <sub>CC</sub> | V <sub>OL</sub> + 0.3 V | V <sub>OH</sub> - 0.3 V |  |  |  |  |  |



| Table 10. Test data |                 |                                 |              |      |                                     |                                     |                                     |  |  |  |
|---------------------|-----------------|---------------------------------|--------------|------|-------------------------------------|-------------------------------------|-------------------------------------|--|--|--|
| Туре                | Input           |                                 | Load         |      | S1 position                         |                                     |                                     |  |  |  |
|                     | VI              | t <sub>r</sub> , t <sub>f</sub> | CL           | RL   | t <sub>PHL</sub> , t <sub>PLH</sub> | t <sub>PZH</sub> , t <sub>PHZ</sub> | t <sub>PZL</sub> , t <sub>PLZ</sub> |  |  |  |
| 74AHC1G125-Q100     | V <sub>CC</sub> | ≤ 3 ns                          | 15 pF, 50 pF | 1 kΩ | open                                | GND                                 | V <sub>CC</sub>                     |  |  |  |
| 74AHCT1G125-Q100    | 3 V             | ≤ 3 ns                          | 15 pF, 50 pF | 1 kΩ | open                                | GND                                 | V <sub>CC</sub>                     |  |  |  |

### 12. Package outline



#### Fig. 7. Package outline SOT353-1 (TSSOP5)

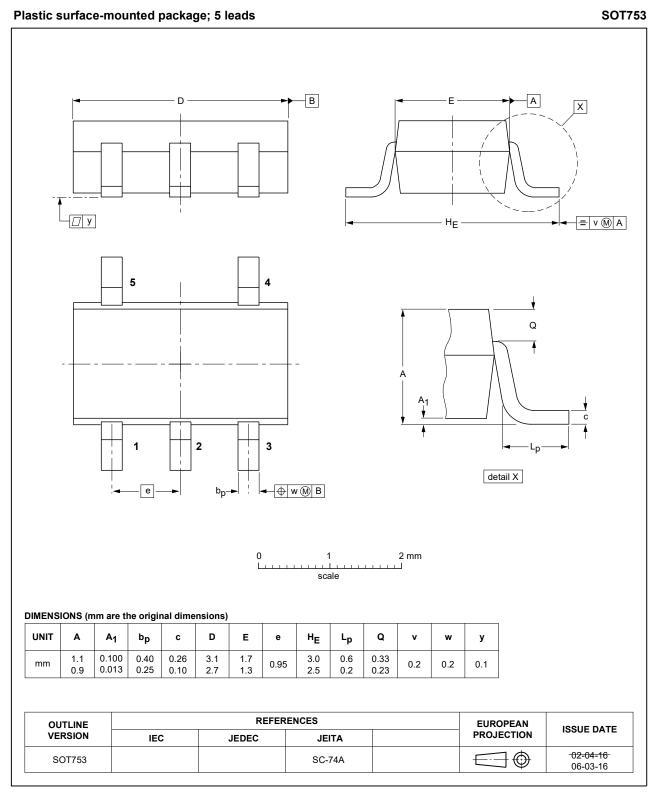
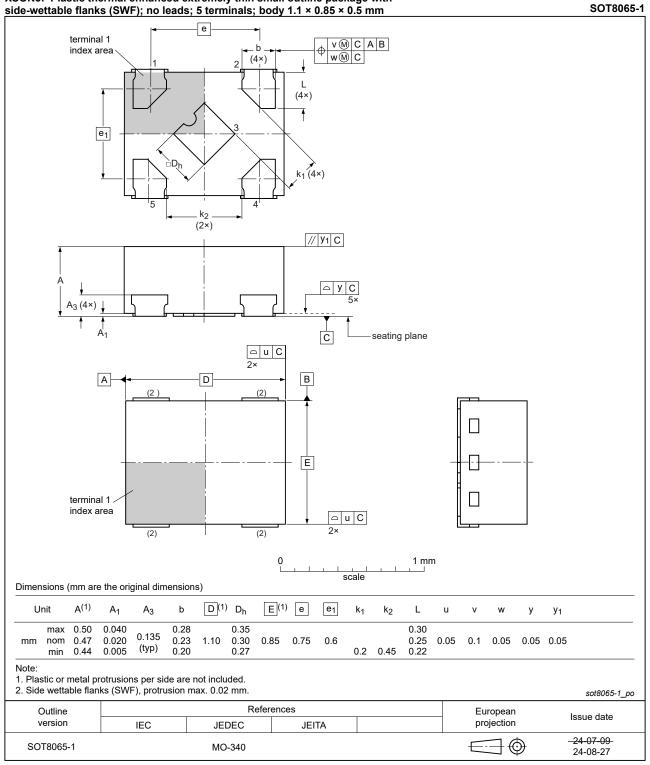


Fig. 8. Package outline SOT753 (SC-74A)

<sup>74</sup>AHC\_AHCT1G125\_Q100



### XSON5: Plastic thermal enhanced extremely thin small outline package with

Fig. 9. Package outline SOT8065-1 (XSON5)

### 13. Abbreviations

| Table 11. Abbreviations |   |  |  |  |
|-------------------------|---|--|--|--|
| Acronym                 | Description                               |  |  |  |
| ANSI                    | American National Standards Institute     |  |  |  |
| CMOS                    | Complementary Metal Oxide Semiconductor   |  |  |  |
| CDM                     | Charged Device Model                      |  |  |  |
| DUT                     | Device Under Test                         |  |  |  |
| ESD                     | ElectroStatic Discharge                   |  |  |  |
| ESDA                    | ElectroStatic Discharge Association       |  |  |  |
| HBM                     | Human Body Model                          |  |  |  |
| JEDEC                   | Joint Electron Device Engineering Council |  |  |  |
| TTL                     | Transistor-Transistor Logic               |  |  |  |

## 14. Revision history

| Table 12. Revision history |   |                    |               |                          |  |  |
|----------------------------|---|--------------------|---------------|--------------------------|--|--|
| Document ID                | Release date  | Data sheet status  | Change notice | Supersedes               |  |  |
| 74AHC_AHCT1G125_Q100 v.6   | 20240919  | Product data sheet | -             | 74AHC_AHCT1G125_Q100 v.5 |  |  |
| Modifications:             | Type number 74AHC1G125GZ-Q100 (SOT8065-1/XSON5) added.  |                    |               |                          |  |  |
| 74AHC_AHCT1G125_Q100 v.5   | 20230915  | Product data sheet | -             | 74AHC_AHCT1G125_Q100 v.4 |  |  |
| Modifications:             | • <u>Section 2</u> : ESD specification updated according to the latest JEDEC standard.  |                    |               |                          |  |  |
| 74AHC_AHCT1G125_Q100 v.4   | 20220111  | Product data sheet | -             | 74AHC_AHCT1G125_Q100 v.3 |  |  |
| Modifications:             | • Fig. 7: Package outline drawing SOT353-1(TSSOP5) has changed  |                    |               |                          |  |  |
| 74AHC_AHCT1G125_Q100 v.3   | 20201013  | Product data sheet | -             | 74AHC_AHCT1G125_Q100 v.2 |  |  |
| Modifications:             | <ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li><u>Section 1</u> and <u>Section 2</u> updated.</li> <li><u>Table 5</u>: Derating values for P<sub>tot</sub> total power dissipation updated.</li> </ul> |                    |               |                          |  |  |
| 74AHC_AHCT1G125_Q100 v.2   | 20121019  | Product data sheet | -             | 74AHC_AHCT1G125_Q100 v.1 |  |  |
| Modifications:             | • <u>Section 2</u> : ESD protection CDM JESD22-C101E changed to MIL-STD-833.  |                    |               |                          |  |  |
| 74AHC_AHCT1G125_Q100 v.1   | 20120807  | Product data sheet | -             | -                        |  |  |

### 15. Legal information

#### **Data sheet status**

| Document status<br>[1][2]         | Product<br>status [3] | Definition  |
|-----------------------------------|-----------------------|---|
| Objective [short]<br>data sheet   | Development           | This document contains data from the objective specification for product development. |
| Preliminary [short]<br>data sheet | Qualification         | This document contains data from the preliminary specification.                       |
| Product [short]<br>data sheet     | Production            | This document contains the product specification.                                     |

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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### 74AHC1G125-Q100; 74AHCT1G125-Q100

#### Bus buffer/line driver; 3-state

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